Correction: Understanding the 2D-material and substrate interaction during epitaxial growth towards successful remote epitaxy: a review

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Following publication of the original article [1], the authors noticed some errors.

In Sect. 4.3, “In-situ 2D growth”, and in caption of Fig. 3, the compound name "h-BN" should be changed to "BN (Boron nitride)" and "graphene" to be changed to "thin amorphous carbon (TAC)". In consistent with the corrections in text and figure caption, Fig. 3 is also updated.

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The original article [1] has been updated.

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